- SN74LS64X-1 Versions Rated at I<sub>OL</sub> of 48 mA
- Bi-directional Bus Transceivers in High-Density 20-Pin Packages
- Hysteresis at Bus Inputs Improves Noise Margins
- Choice of True or Inverting Logic
- Choice of 3-State or Open-Collector Outputs

DEVICE	OUTPUT	LOGIC
'LS640	3-State	Inverting
'LS641	Open-Collector	True
'LS642	Open-Collector	Inverting
'LS644	Open-Collector	True and inverting
'LS645	3-State	True

#### description

These octal bus transceivers are designed for asynchronous two-way communication between data buses. The devices transmit data from the A bus to the B bus or from the B bus to the A bus depending upon the level at the direction control (DIR) input. The enable input  $\overline{(G)}$  can be used to disable the device so the buses are effectively isolated.

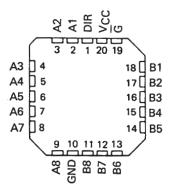
The -1 versions of the SN74LS640 thru SN74LS642, SN74LS644, and SN74LS645 are identical to the standard versions except that the recommended maximum I<sub>QL</sub> is increased to 48 milliamperes. There are no -1 versions of the SN54LS640 thru SN54LS642, SN54LS644, and SN54LS645.

The SN54LS640 thru SN54LS642, SN54LS644, and SN54LS645 are characterized for operation over the full military temperature range of  $-55\,^{\circ}\text{C}$  to  $125\,^{\circ}\text{C}$ . The SN74LS640 thru SN74LS642, SN74LS644, and SN74LS645 are characterized for operation from  $0\,^{\circ}\text{C}$  to  $70\,^{\circ}\text{C}$ .

SN54LS' . . . J PACKAGE SN74LS' . . . DW OR N PACKAGE (TOP VIEW)

DIR[	1 (	20	Dvcc
A1[	2	19	□G
A2[	3	18	<b>□</b> B1
A3[	4	17	<b>□</b> B2
A4[	5	16	B3
A5[	6	15	<b>□</b> B4
A6[	7	14	<b>□</b> B5
A7[	8	13	<b>□</b> в6
A8[	9	12	B7
GND	10	11	<b>□</b> B8
			-

SN54LS' . . . FK PACKAGE (TOP VIEW)



**FUNCTION TABLE** 

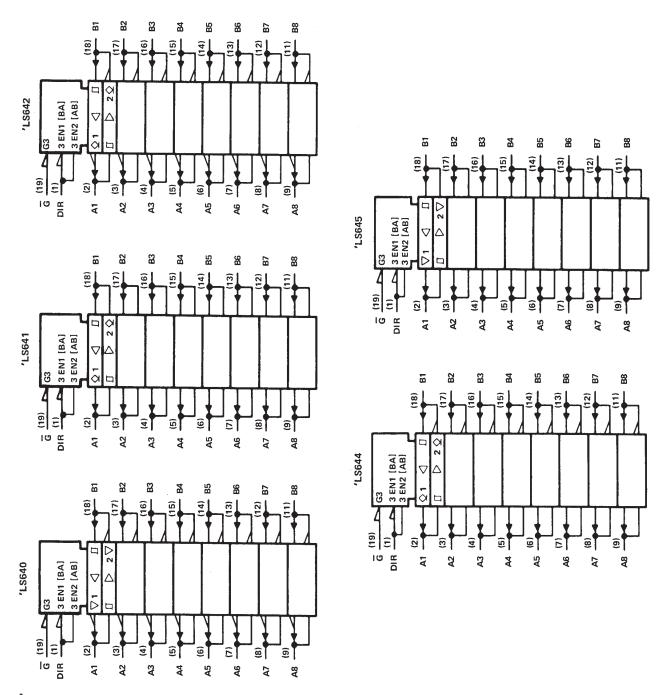
CO	NTROL		OPERATION	
INPUTS G DIR		'LS640	'LS641	0.0044
		'LS642	'LS645	'LS644
L	L	B data to A bus	B data to A bus	B data to A bus
L	Н	A data to B bus	A data to B bus	Ā data to B bus
Н	X	Isolation	Isolation	Isolation

H = high level, L= low level, X = irrelevant



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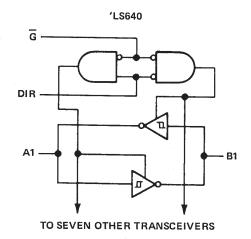
### logic symbols†

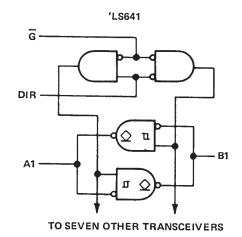


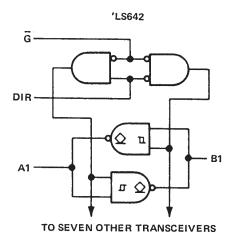
 $<sup>^\</sup>dagger$  These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for DW, J, and N packages.

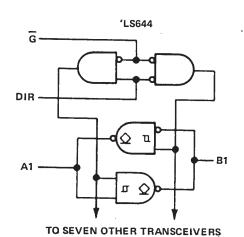


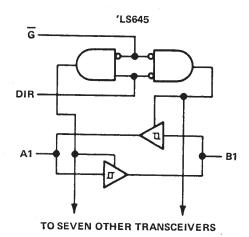
### logic diagrams (positive logic)













### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC (see Note 1)	٧
Input voltage: All inputs	V
I/O ports	
Operating free-air temperature range: SN54LS640, SN54LS64555°C to 125°	٥С
SN74LS640, SN74LS645 0 °C to 70 °C	°C
Storage temperature range65°C to 150°C	°C

NOTE 1: Voltage values are with respect to network ground terminal.

### recommended operating conditions

	PARAMETER		SN54LSG		SN74LS640 SN74LS645			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
Vcc	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
VIH	High-Ivel input voltage	2			2			V
VIL	Low-level input voltage			0.5			0.6	V
ЮН	High-level output current			12			<b>– 15</b>	mA
loL	Low-level output current			12			24	
-01							48†	mA
TA	Operating free-air temperature	- 55		125	0		70	°C

<sup>&</sup>lt;sup>†</sup>The 48-mA limit applies for the SN74LS640-1 and SN74LS645-1 only.

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

P	PARAMETER	ТЕ	TEST CONDITIONS‡			SN54LS640 SN54LS645			SN74LS640 SN74LS645			
					MIN	TYP§	MAX	MIN	TYP§	MAX	1	
VIK		V <sub>CC</sub> = MIN,	$I_1 = -18 \text{ mA}$				- 1.5			- 1.5	V	
Hyste (V <sub>T+</sub> –		V <sub>CC</sub> = MIN,		A or B input	0.1	0.4		0.2	0.4		V	
Voн		V <sub>CC</sub> = MIN,	V <sub>IH</sub> = 2 V,	I <sub>OH</sub> = -3 mA	2.4	3.4		2.4	3.4			
VOH		VIL = MAX		IOH = MAX	2			2			1	
	V <sub>CC</sub> = MIN,	V = 2 V	I <sub>OL</sub> = 12 mA		0.25	0.4		0.25	0.4	1		
VOL	VOL	VIL = MAX		IOL = 24 mA					0.35	0.5	] v	
				IOL = 48 mA#					0.4	0.5		
lozh		V <sub>CC</sub> = MAX,		V <sub>O</sub> = 2.7 V			20			20	μΑ	
lozL		V <sub>CC</sub> = MAX,	$\overline{\mathbb{G}}$ at 2 V,	V <sub>O</sub> = 0.4 V			- 0.4			- 0.4	mA	
l <sub>l</sub>	A or B	V <sub>CC</sub> = MAX		V <sub>1</sub> = 5.5 V			0.1			0.1		
'1	DIR or G	VCC WAX		V <sub>1</sub> = 7 V			0.1			0.1	mA	
IH		V <sub>CC</sub> = MAX,	V <sub>IH</sub> = 2.7 V				20			20	μΑ	
L		V <sub>CC</sub> = MAX,	V <sub>IL</sub> = 0.4 V				- 0.4			- 0.4	mA	
los¶		V <sub>CC</sub> = MAX			- 40		- 225	- 40		- 225	mA	
	Outputs high					48	70		48	70	<b> </b>	
Icc	Outputs low	$V_{CC} = MAX$ ,	Outputs open			62	90		62	90	mA	
	Outputs at Hi-Z					64	95		64	95	1	

<sup>&</sup>lt;sup>†</sup>For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

<sup>\*</sup>The 48-mA condition applies for the SN74LS640-1 and SN74LS645-1 only.



 $<sup>^{\</sup>S}$ All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25 °C.

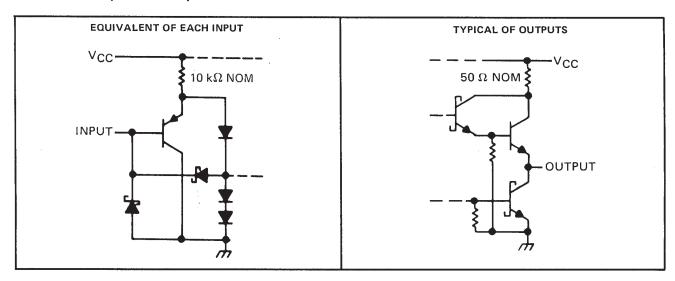
Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second.

## switching characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25 \,^{\circ}\text{C}$

	PARAMETER	FROM	TO	TEST	′LS64	10, 'LS6	640-1	'LS64	5, 'LS6	45-1	UNIT
	PARAMETER	(INPUT)	(OUTPUT)	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
10	Propagation delay time,	Α	В			6	10		8	15	
tPLH	low-to-high-level output	В	Α	1		6	10		8	15	ns
<b>†</b> D. 11	Propagation delay time,	Α	В	$C_1 = 45  pF$		8	15		11	15	
tPHL	high-to-low-level output	В	А	-		8	15		11	15	ns
100	Output enable time to	G	Α	$R_L = 667 \Omega$ , See Note 2		31	40		31	40	ns
tPZL	low level	G	В	See Note 2		31	40		31	40	
+	Output enable time to	G	А			23	40		26	40	
<sup>t</sup> PZH	high level	G	В			23	40		26	40	ns
+	Output disable time	Ğ	Α	C F - F		15	25		15	25	
<sup>t</sup> PLZ	from low level	G	В	$C_L = 5 pF$ ,	· ·	15	25		15	25	ns
+	Output disable time	G	Α	$R_L = 667 \Omega$ ,		15	25		15	25	
tPHZ	from high level	G	В	See Note 2		15	25		15	25	ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

### schematics of inputs and outputs



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### TYPICAL CHARACTERISTICS

# \$N54LS' INVERTING OUTPUT VOLTAGE

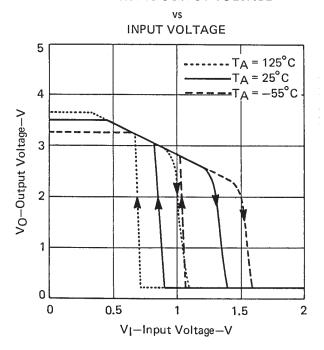


FIGURE 1

## SN54LS' NONINVERTING OUTPUT VOLTAGE

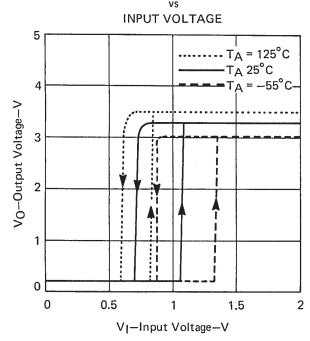


FIGURE 3

# SN74LS' INVERTING OUTPUT VOLTAGE

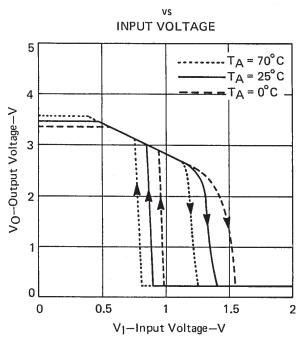


FIGURE 2

# SN74LS' NONINVERTING OUTPUT VOLTAGE

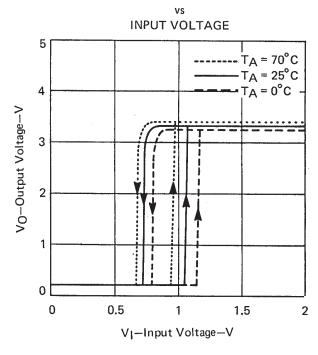


FIGURE 4



## SN54LS641, SN54LS642, SN54LS644 SN74LS641, SN74LS642, SN74LS644 OCTAL BUS TRANSCEIVRS WITH OPEN-COLLECTOR OUTPUTS

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## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC (see Note 1)	7V
Input voltage: All inputs and I/O ports	7 V
Operating free-air temperature range: SN54LS641, SN54LS642, SN54LS644	125° C
SN74LS641, SN74LS642, SN74LS644 0° C to	
Storage temperature range	150° C

NOTE 1: Voltage values are with respect to network ground terminal.

### recommended operating conditions

	PARAMETER		SN54LS641 SN54LS642			SN74LS641 SN74LS642		
			SN54LS	644	s	N74LS	644	ļ
		MIN	NOM	MAX	MIN	NOM	MAX	Ī
Vcc	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			0.5			0.6	V
Vон	High-level output voltage			5.5			5.5	V
loL	Low-level output current			12			24	
.OL	work for or output outfort						48 §	mA
$T_A$	Operating free-air temperature	- 55		125	0		70	°C

The 48 mA limit applies for the SN74LS641-1, SN74LS642-1, and SN74LS644-1 only.

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS†		SN54LS641 SN54LS642 SN54LS644			SN74LS641 SN74LS642 SN74LS644			UNIT
				MIN	TYP‡	MAX	MIN	TYP‡	MAX	
VIK		V <sub>CC</sub> = MIN,	I <sub>I</sub> = - 18 mA			- 1.5			- 1.5	V
Hysteres (V <sub>T+</sub> – V-		V <sub>CC</sub> = MIN,	A or B input	0.1	0.4		0.2	0.4		٧
ЮН		V <sub>CC</sub> = MIN, V <sub>IL</sub> = MAX,	V <sub>IH</sub> = 2 V, V <sub>OH</sub> = 5.5 V			0.1			0.1	mA
		V <sub>CC</sub> = MIN,	I <sub>OL</sub> = 12 mA		0.25	0.4		0.25	0.4	
VOL		V <sub>1H</sub> = 2 V,	IOL = 24 mA					0.35	0.5	V
		VIL = MAX	IOL = 48 mA §					0.4	0.5	
11	A or B	V <sub>CC</sub> = MAX	V <sub>I</sub> = 5.5 V			0.1			0.1	_
'1	DIR or G	ACC - IMAY	V <sub>I</sub> = 7 V			0.1			0.1	mA
lн		V <sub>CC</sub> = MAX,	V <sub>I</sub> = 2.7 V			20			20	μА
ηL		V <sub>CC</sub> = MAX,	V <sub>1</sub> = 0.4 V			- 0.4			- 0.4	mΑ
	Outputs high				48	70		48	70	
Icc	Outputs low	V <sub>CC</sub> = MAX,	Outputs open		62	90		62	90	mA
	Outputs at Hi-Z				64	95		64	95	

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

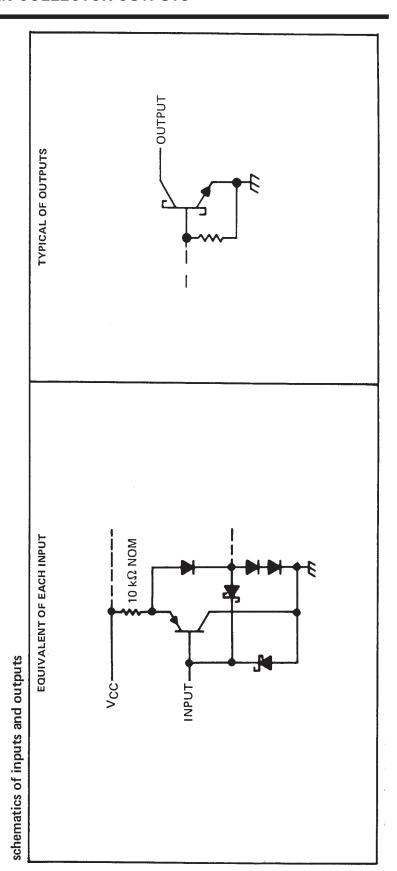


<sup>‡</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ} \text{C}$ .

<sup>§</sup>The 48 mA condition applies for the SN74LS641-1, SN74LS642-1, and SN74LS644-1 only.

1			e E		ž.		se S		sc C
644-1	MAX	25	25	25	25	4	40	09	22
LS644, 'LS644-1	TYP	17	19	14	16	26	25	43	37
J.TSE	MIN								
642-1	MAX	25	25	25	25	40	40	9	09
'LS642, 'LS642-1	TYP	19	19	7	14	56	28	43	39
,rse	N								
641-1	MAX	25	25	25	25	40	40	20	20
'LS641, 'LS641-1	TYP	17	17	16	16	23	25	34	37
	Z								
TECT CONDITIONS				, 145 PJ,	0 1 9	] nL = 007 32,	200	Z aloni aac	
10	(OUTPUT)	В	۷.	8	٧	٧	В	∢	В
FROM	(INPUT)	٨	В	A	В	G, DIR	Ğ, DIR	G, DIR	G, DIR
PARAMETER		Propagation delay time,	PLH low-to-high-level output	Propagation delay time,	PHE high-to-low-level output	Output disable time	FLH from low level	Output enable time	the from high level

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.





switching characteristics at VCC = 5 V, TA = 25  $^{\circ}$  C

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